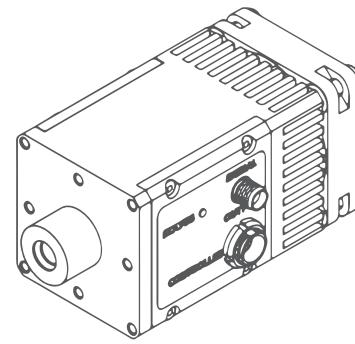


LabM-I-10.6

Programmable IR detection module based on HgCdTe TE cooled optically immersed photovoltaic multi-junction detector



FEATURES

- Spectral range: 2.0 to 12.0 μm
- Frequency bandwidth: DC to 120 MHz (typ.)
- High performance and reliability
- DC offset compensation
- Built-in fan
- M4 mounting hole
- Compatible with optical accessories
- Versatility and flexibility
- Quantity discounted price
- Fast delivery
- No minimum order quantity required

APPLICATIONS

- Gas detection, monitoring and analysis: SO_2 , NH_3 , SF_6
- CBRN threats detection
- CO_2 laser measurements: power monitoring and control, beam profiling and positioning, calibration
- Free-space optical communication
- FTIR spectroscopy
- Medical bacteria identification
- Dentistry
- Glucose sensing
- Research and prototyping

PROGRAMMABLE PARAMETERS

- Gain: in the 40 dB range
- Bandwidth: 1.5 MHz/15 MHz/120 MHz (typ.)
- Coupling: AC/DC
- Detector's temperature
- Output voltage offset

DETECTION MODULE CONFIGURATION

Detection module symbol	LabM-I-10.6
Detector symbol	PVMI-4TE-10.6-1x1-T08-wZnSeAR-36 (p. 66)
Detector type	photovoltaic, multi-junction
Active element material	epitaxial HgCdTe heterostructure
Optical area, A_o	1 mm × 1 mm
Immersion	hyperhemisphere
Cooling	4TE
Acceptance angle, Φ	~36 deg.
Window	wZnSeAR (3 deg. wedged zinc selenide, anti-reflection coating)
Preamplifier symbol	PIP (p. 129)
Preamplifier type	transimpedance, programmable
Signal output socket	SMA
Power supply, TE cooler, thermistor and fan socket	LEMO ECG.0B.309.CLN

INCLUDED ACCESSORIES

- 1 pc of SMA-BNC cable
- 1 pc of LEMO-DB9 cable

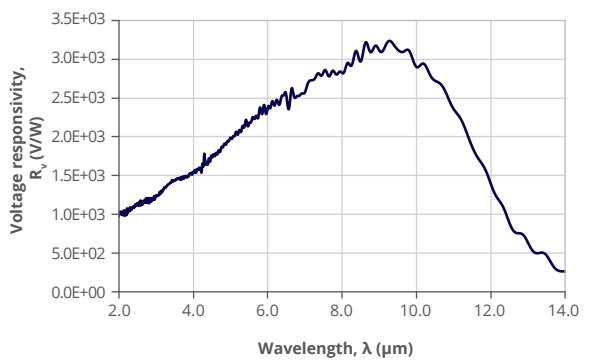
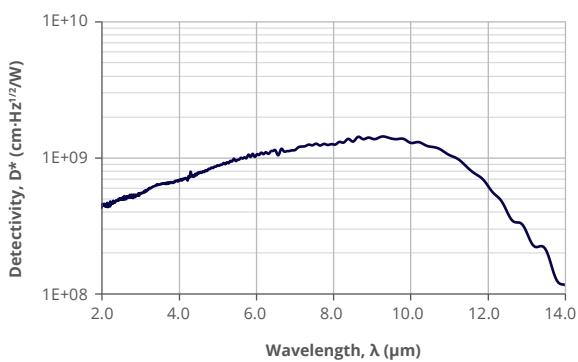
DEDICATED ACCESSORIES

- PTCC-01 series TEC controller: obligatory (p. 145)
- Smart Manager software: freeware
- OTA optical threaded adapter (p. 155)
- DRB-2 base mounting system (p. 152)

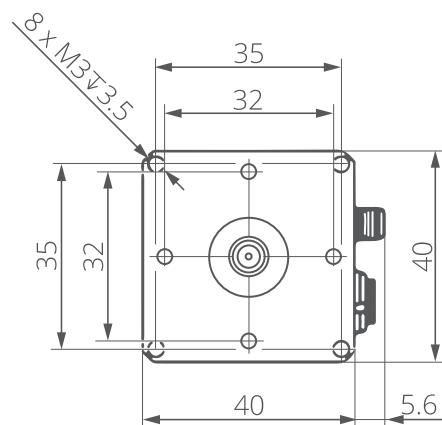
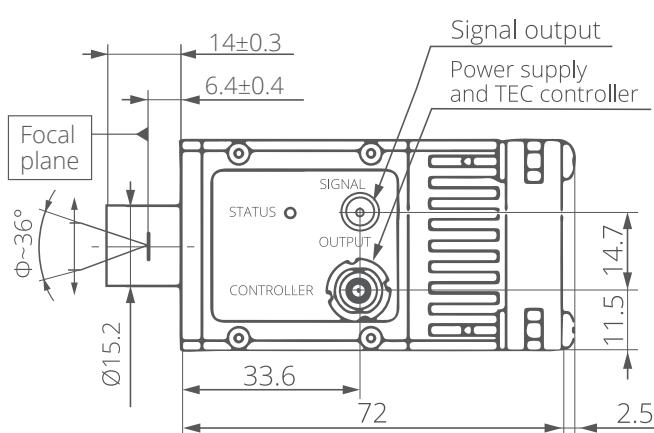
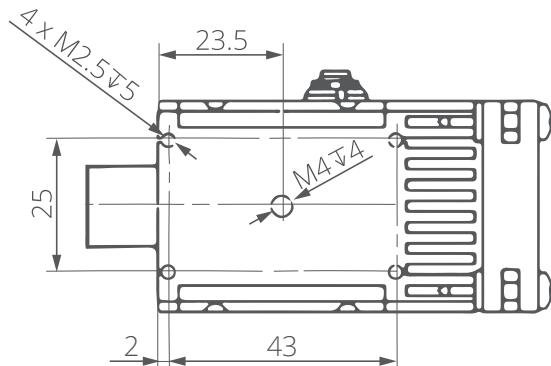
SPECIFICATION ($T_{\text{amb}} = 293 \text{ K}$, $R_{\text{load}} = 50 \Omega$, unless otherwise noted; default module settings)

Parameter	Test conditions/remarks	Value			Unit
		Min.	Typ.	Max.	
Active element temperature, T_{chip}		-	200	-	K
Cut-on wavelength, $\lambda_{\text{cut-on}} (10\%)$	At 10% of peak responsivity	-	2.0	-	μm
Peak wavelength, λ_{peak}		8.0	9.0	10.0	μm
Specific wavelength, λ_{spec}		-	10.6	-	μm
Cut-off wavelength, $\lambda_{\text{cut-off}} (10\%)$	At 10% of peak responsivity	-	12.0	-	μm
Detectivity, D^*	At $\lambda = \lambda_{\text{peak}}$, $f = 10 \text{ MHz}$	-	1.4×10^9	-	$\text{cm} \cdot \text{Hz}^{1/2} / \text{W}$
	At $\lambda = \lambda_{\text{spec}}$, $f = 10 \text{ MHz}$	6.0×10^8	1.2×10^9	-	$\text{cm} \cdot \text{Hz}^{1/2} / \text{W}$
Output noise voltage density, v_n	At $f = 10 \text{ MHz}$	-	-	400	$\text{nV} / \text{Hz}^{1/2}$
Voltage responsivity, R_v	At $\lambda = \lambda_{\text{peak}}$	-	3.2×10^3	-	V/W
	At $\lambda = \lambda_{\text{spec}}$	1.8×10^3	2.7×10^3	-	V/W
Low cut-off frequency, $f_{\text{lo-DC}}$	DC coupling selected	-	0	-	Hz
Low cut-off frequency, $f_{\text{lo-AC}}$	AC coupling selected	-	10	-	Hz
High cut-off frequency, $f_{\text{hi-H}}$	High bandwidth selected	80	120	-	MHz
High cut-off frequency, $f_{\text{hi-M}}$	Mid bandwidth selected	-	15	-	MHz
High cut-off frequency, $f_{\text{hi-L}}$	Low bandwidth selected	-	1.5	-	MHz
Output impedance, R_{out}		-	50	-	Ω
Output voltage swing, V_{out}		-	-	±1	V
Output voltage offset, V_{off}		-	-	±20	mV
Power supply voltage (positive), $+V_{\text{sup}}$		-	+9	-	V
Power supply voltage (negative), $-V_{\text{sup}}$		-	-9	-	V
Power supply current consumption (positive), $+I_{\text{sup}}$		-	-	+100	mA
Power supply current consumption (negative), $-I_{\text{sup}}$		-	-	-100	mA
Fan power consumption, P_{fan}		-	-	900	mW
TEC voltage, V_{TEC}		-	-	8.3	V
TEC current, I_{TEC}		-	-	0.4	A
Weight		-	180	-	g

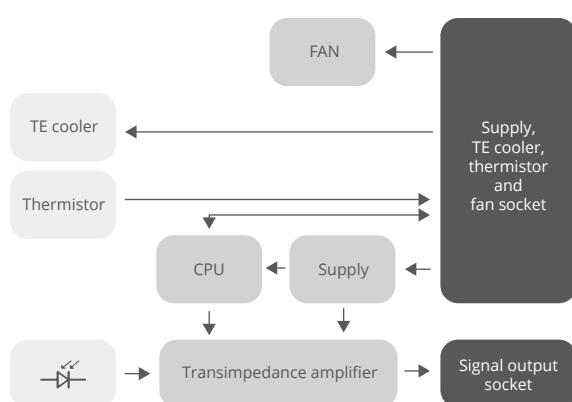
SPECTRAL RESPONSE (Typ., $T_{\text{amb}} = 293 \text{ K}$, $T_{\text{chip}} = 200 \text{ K}$)



MECHANICAL LAYOUT (Unit: mm)



SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions/ remarks	Value	Unit
Ambient operating temperature, T_{amb}		10 to 30	°C
Storage temperature, T_{stg}		-20 to 50	°C
Humidity	No dew condensation	10 to 90	%
Maximum incident optical power density	Continuous wave (CW) or single pulses >1 µs duration	2.5	W/cm ²
	Single pulses <1 µs duration	10	kW/cm ²

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device.